Gapless unidirectional photonic transport using all-dielectric kagome lattices

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Photonic topological insulators are a promising photonic platform due to the possibility of unidirectional edge states with insensitivity to bending, fabrication imperfections, or environmental fluctuation. Here we demonstrate highly efficient unidirectional photonic edge mode propagation facilitated by an optical analog of the quantum valley Hall effect. With an all-dielectric kagome lattice design, we demonstrate broadband suppressed reflection in the presence of sharp corners and further show negligible vertical losses in a semiconductor-based device at telecommunication wavelengths.

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When propagating in a (structured) material or waveguide, not all of the light travels in this initial direction but parts of it experience such back-reflection due to bending, fabrication defects, or environmental variations. For most applications, back-propagation should be avoided and it is thus not surprising that the unique properties of photonic topological insulators (PTIs) [1,2] have attracted widespread attention due to their promise to prohibit back-reflections. The basis of such back-scattering-free one-way waveguides lies at the interface of two topologically inequivalent photonic crystals (PhCs) which exhibit topological edge modes that—guaranteed by the bulk-boundary correspondence [3]—propagate only in one direction and are at the same time robust against perturbations. Not surprisingly, a plethora of possible topologically nontrivial photonic designs has been put forward, involving nonreciprocal systems [4], complex metamaterials [5], the Floquet topological insulator principle [6], and an artificial magnetic gauge [7,8]. However, the aforementioned PTIs need strong magnetic fields, are complicated to fabricate, and/or are difficult if not impossible to scale to optical frequencies.

As an alternative, a deformed honeycomb-based topological PhC [9], which emulates the quantum spin Hall effect (QSHE) [9–12] has recently gained interest, not least due to its simple fabrication as compared to other PTIs. Nevertheless, while 2D hexagonal symmetries (such as the honeycomb-based topological PhC) generally lead to Dirac cones at the \( K \) and \( K' \) points of the Brillouin zone (BZ), and with a geometrical perturbation it is possible to lift the pointlike degeneracies in order to obtain a nontrivial topological and complete photonic band gap [13] (which leads to topological protection defined within the parameter space of a certain type of a deterministic geometrical perturbation that differs from the traditional Hatsugai sense [3]), there is an inherent problem. The pseudo-time-reversal antiunitary operator \( T^2 = -1 \), introduced to have well-defined orthogonal spin up/down channels, is constructed on the basis of the sixfold rotation \( (C_6) \) operator of the crystal. However, the \( C_6 \) symmetry of the crystal is broken in any finite, truncated, configuration and the spin up and spin down channels couple to each other. Consequently, while edge modes are guaranteed at the interface between the two topologically distinct deformed honeycomb PhCs, for most frequencies within the band gap, there is an anticrossing in their dispersion and they eventually do suffer from intrinsic back-reflection. Yet, starting from a \( C_6 \) symmetry with symmetry protected Dirac cones, it can be shown that there are two routes towards breaking the symmetry to open a topological band gap without breaking optical reciprocity [13]: one related to the aforementioned QSHE [10], and the other to the quantum valley Hall effect (QVHE) [14]. The QVHE has been widely studied in photonic and mechanical systems with staggered honeycomb [15–21] lattice, triangular rods [22–24], or multipod [25–27] structure.

Here, we introduce an all-dielectric PTI based on a kagome lattice [28] that naturally lends itself to QVHE symmetry breaking [13], while being composed of monodisperse rods of a single dielectric material. Compared to the QVHE designs of triangular-like holes/rods array and staggered honeycomb structures, the proposed perturbed kagome lattice requires a single monodisperse type of circular holes/rods and is thus easier fabricated. It is this simplicity of the kagome-based design in terms of fabrication and its unidirectional edge mode transport which makes it an ideal candidate for practical applications at near-infrared and visible wavelengths. Here, we present and model the predicted behavior for an on-chip platform that can be readily fabricated with state-of-the-art semiconductor growth techniques [29].
To describe the band gap opening more rigorously, we adopt a perturbation-based group theoretical approach detailed in Refs. [13, 31] to the hexagonal wallpaper group $p6mm$ (17). Then, an effective Hamiltonian is derived for a (small) geometrical perturbation, $\delta$, and close to $K$, $\delta k = (\delta k_x, \delta k_y, \delta k_z)$, in the canonical basis of the induced $K$ irreducible representation (irrep) from the 2D little group irrep of $p6mm$ [32]:

$$
H_{kagome} = \delta k_x \gamma_1 - \delta k_y \gamma_2 + \delta \gamma_5 = \begin{pmatrix}
\mathcal{W}_K & 0 \\
0 & \mathcal{W}_K
\end{pmatrix},
$$

where $\gamma_1 := \sigma_3 \otimes \sigma_3, \gamma_2 := \sigma_3 \otimes \sigma_1, \gamma_3 := \sigma_1 \otimes \mathbb{1}, \sigma_1 := \sigma_2 \otimes \mathbb{1}$, and $\gamma_5 := \sigma_3 \otimes \sigma_3$ are matrices satisfying a Clifford algebra generated by the vector field spanned by the $\gamma_1$, with the associated anticommutation relation $\{\gamma_1, \gamma_j\} = 2\delta_{ij} \mathbb{1}_4$. $\mathcal{W}_K$ is necessarily block-diagonal [32] in its canonical basis as in the case with the QSHE Kane-Mele Hamiltonian [10], because translation symmetry is not broken with the perturbation. It does not mix the $K'/K$ point as is the case for $O_h$ deformed kagome lattice, for example [15–20, 22–27]:

$$
C_{K/K'} = \frac{1}{2\pi} \int_{S_{K/K'}} \mathcal{F}(k) \, d^2k.
$$

The integration is performed over the two valley domains $S_{K/K'}$ defined in Fig. 2 as the two triangles which together form the dual of the standard hexagonal BZ tessellation of reciprocal space. The integrand is the Berry curvature [33] $\mathcal{F}(k) = \nabla \times i \mathbf{u}_k \times \nabla \mathbf{u}_k$. Note that $C_{K/K'}$ is not a quantized topological invariant because $S_{K/K'}$ is not a closed surface, so that the Chern theorem does not hold. Figure 2 shows the Berry curvatures calculated for a positively ($\delta = +0.15$) and negatively ($\delta = -0.15$) deformed kagome lattice, for $k$ points in the reciprocal primitive unit cell. They are directly calculated from the numerical field profile using a Wilson loop approach to numerically avoid random gauge dependence (see Ref. [34] for the details of the calculation). The valley Chern number obtained for positive (negative) perturbation by integrating around the $K/K'$ are then $C_{K/K'} = \pm 0.18$ ($C_{K/K'} = \mp 0.18$). It can be shown that the valley Chern number depends on the perturbation strength, and explains why we can only get a valley Chern number $C_{K/K'} = \pm 1/2$ for
FIG. 2. Calculated Berry curvatures in the reciprocal primitive unit cell, using a Wilson loop approach for (a) positively and (b) negatively perturbed kagome lattices. The dashed line represents the limit of the reciprocal primitive unit cell and the dotted black line defines the boundary for the regions of integration $S_{K/K'}$ in Eq. (2).

infinitesimal perturbation, as reported before [15–20,22–27] (see Ref. [34] for more details on the valley Chern number).

Although the valley Chern number is not a topological invariant, a strong bulk-boundary correspondence similar to Ref. [3] exists in the extended parameter space ($-\delta k_y, \delta, \delta k_x$) where Weyl charges of opposite chirality lead to guaranteed edge modes in the $K/K'$ valleys, respectively [13]. These Weyl charges can be correlated one-to-one to the sign of the valley Chern numbers, which can thus be interpreted as a topological integer with associated bulk-boundary correspondence. In contrast to Ref. [3], however, the existence of the strong correspondence in the extended parameter space only fixes crystal termination and is only valid for inclinations for which the $K$ and $K'$ point are not projected to the same point in the edge BZ (cf. BZ insets in Fig. 3). The bulk-boundary correspondence thus reduces to the weaker form which rigorously valid only for specific well-defined boundaries. From the expression of the effective Hamiltonian $H_{\text{kagome}}$, it is evident that a nontrivial Weyl charge is located at the $K$ and $K'$ points which has opposite signs because $W_K = -W_K'$ and which has opposite signs for opposite perturbation strength. As a consequence, and from Fig. 2, starting with an unperturbed lattice and then perturbing positively on one side of a chosen interface and negatively on the other could potentially lead to topological edge modes at most frequencies.

Figure 3 shows the corresponding supercell band structure for $\delta = \pm 0.15$ and for different interface inclinations. The solid blue lines correspond to the bulk modes and the solid colored lines correspond to topological edge modes inside the bulk band gap. This figure shows that an anticrossing arises when the $K/K'$ points are projected onto the same $k_\parallel$ points [$\Gamma$-$M$ inclination, Fig. 3(b)] while a crossing arises for $\Gamma$-$K$ inclination [Fig. 3(a)]. In the $\Gamma$-$K$ inclination case [Fig. 3(a)], each interface supports two counter-propagating edge modes corresponding to the well-defined pseudospin up (down) edge modes of the $K$ ($K'$) valleys. These result from the opposite Weyl charges at the $K$ (or $K'$) point for two sides of the interface [3,13]. In the $\Gamma$-$M$ inclination case [Fig. 3(b)], however, the pseudospin separation breaks down and the edge modes suffer from back-scattering, similarly to the honeycomb PhC [9].

We here demonstrate broadband back-scattering-immunity numerically in Fig. 4 for finite perturbations, going beyond what has been shown rigorously for infinitesimal perturbation strengths with our generic theory based on symmetry only. The unidirectional propagation with negligible intervalley
coupling is demonstrated by studying the transmission through waveguides with bendings of different inclinations. Figures 4(a) and 4(b) shows two examples of waveguides oriented in a $\Gamma$-$K$ inclination direction in which a bending is introduced such that the projected wave vectors of $K$ and $K'$ onto the $k_\parallel$ line are distinct in a Z-shaped design [Fig. 4(a), inset Fig. 3(a)], or fall onto the same point along the vertical interface in a staircase-shaped design [Fig. 4(b), inset Fig. 3(b)]. In the case of the Z-shaped waveguide, we focus on the red interface highlighted in Fig. 3(a) (which is not equivalent to the green interface). Figure 4(c) shows the normalized transmitted flux at the end of the waveguides, obtained using \textit{MIT electromagnetic equation propagation (MEEP)} [35]. At high frequencies, around the upper edge of the photonic band gap, large oscillations are observed due to the presence of additional modes that couple with the two valley channels (see Fig. 3 and Ref. [34] for more information on the modal transmissions). The transmission for the Z-shaped waveguide (solid red line) is of the same order of magnitude as for a straight waveguide with no bending (solid black line) for most of the frequencies inside the band gap (represented by the grey shaded region). In contrast, the staircase-shaped bending (solid blue line) leads to substantial back-reflection resulting in lower transmission because of the non-negligible inter-valley couplings on the $\Gamma$-$M$ inclination interface. This $\Gamma$-$M$ inclination bending additionally introduces a band gap in the dispersion where the edge mode cannot propagate. Broadband robust transmission is therefore achieved for the $\Gamma$-$K$ inclination and in practice the orthogonality of two pseudo-spin channels at the wave vectors away from $K/K'$ is as good as at $K/K'$. Figure 4(d) shows the power profile for a mode propagating along the interface with bendings at frequency $\omega = 0.37(2\pi c/a)$ with negligible back-reflection. Here, the unidirectional edge mode has been excited using a rotating magnetic point dipole source [9,36] and the spatial position of the source has been determined using a chirality map [37] (see Ref. [34] for more details on the chirality map).

From a practical point of view, for the case of a $\Gamma$-$K$ interface inclination, edge modes lie close to or below the light line, thus improving vertical mode confinement without the need of sandwiching the waveguides with mirrors [9]. To make use of the better confinement, we propose a design composed of an InGaAsP free-standing PhC slab ($n = 3.3$ [29]) of 170-nm thickness. Fabrication of this structure can be carried out using a III-V semiconductor wafer consisting of an InGaAsP substrate. The pattern of the air holes can be defined by standard electron-beam lithography and inductively coupled plasma reactive-ion etching. Importantly, the proposed structure can be designed to work at telecommunication wavelengths, from 1.2 to 1.8 $\mu$m, as illustrated in Fig. 5. The supercell band structure for TE-like modes (even-symmetric electric fields) is calculated with a finite-difference time-domain (FDTD) solver [38] for a lattice
constant $a = 0.5 \, \mu m$, air-holes with diameter $d = 0.3a = 150 \, nm$ and perturbation $\delta = \pm 0.15$. The band gap ranges from $1.48$ to $1.58 \, \mu m$ corresponding to a mid-gap at $1.53 \, \mu m$. Since the materials are assumed to be lossless in our simulations, any temporal decay, quantified by $\gamma$ in $E(t) \propto e^{i(\omega t+\gamma x)}$, is due to the leakiness of the mode. The inset of Fig. 5 shows the slope of the curves corresponding to $\gamma$, and demonstrating a negligible $\gamma_B$ for the mode below the light line (point $B$), whereas a finite leakage $\gamma_A$ is present for the mode lying above the light line (point $A$). Figures 6(a) and 6(b) show the electric field distribution corresponding to the point $B$ in Fig. 5. Out-of-plane confinement is guaranteed by the mode’s presence below the light line.

In summary, we have introduced a new kagome-like photonic topological insulator emulating the optical analog of the quantum valley Hall effect. We have numerically shown that the associated topological edge modes do not intrinsically suffer from back-scattering for tailored inclinations. For $\Gamma$-$K$ inclination, the coupling between pseudospin channels is shown to be negligible while edge modes are guaranteed in the center of the band gap. Based on our theoretical predictions, we have presented a realistic 3D design that can be fabricated with state-of-the-art methods [29], and works at suitable wavelengths for telecommunication applications. We have demonstrated improved vertical confinement due to edge modes lying below the light line. The simplicity of the proposed design structure due to its monodisperse rods/holes makes it possible to fabricate it using many conventional techniques such as selective-area epitaxy or electron-beam patterning. We have also shown that possible challenges resulting from low filling ratio can be overcome by tuning the perturbation making the band gap of about $100 \, nm$ at telecommunication wavelengths. Work has been done on kagome lattice in photonic systems [39]. Complementing previous work with kagome lattices, we have provided an in-depth analysis by explaining the reason of possible back-reflection translated in the transmission spectra and analyzing the out-of-plane loss in 3D realistic design.

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[34] See Supplemental Material at http://link.aps.org/supplemental/10.1103/PhysRevResearch.2.012011 for further details on the method used to compute the Berry curvature, the numerical valley Chern number, the transmission spectra, and the chirality map.